

*The
United
States
of
America*



The Commissioner of Patents
and Trademarks

*Has received an application for a patent
for a new and useful invention. The title
and description of the invention are en-
closed. The requirements of law have
been complied with, and it has been de-
termined that a patent on the invention
shall be granted under the law.*

Therefore, this

United States Patent

*Grants to the person or persons having
title to this patent the right to exclude
others from making, using or selling the
invention throughout the United States
of America for the term of seventeen
years from the date of this patent, sub-
ject to the payment of maintenance fees
as provided by law.*

Bence Lehman

Commissioner of Patents and Trademarks

Marquie V. Turner

Attest



US005444305A

United States Patent [19]

Matsui

[11] **Patent Number:** 5,444,305
[45] **Date of Patent:** Aug. 22, 1995

[54] SEMICONDUCTOR MEMORY CIRCUIT

[75] Inventor: Yoshinori Matsui, Tokyo, Japan

[73] Assignee: NEC Corporation, Tokyo, Japan

[21] Appl. No.: 84,017

[22] Filed: Jun. 30, 1993

[30] Foreign Application Priority Data

Jun. 30, 1992 [JP] Japan 4-172229

[51] Int. Cl.⁶ G11C 7/00

[52] U.S. Cl. 365/207; 365/189.01;
365/221; 365/230.03; 365/230.04

[58] Field of Search 365/189.01, 230.03,
365/221, 207, 230.04, 196

[56] References Cited

U.S. PATENT DOCUMENTS

4,807,194 2/1989 Yamada et al. 365/207
5,243,574 9/1993 Ikeda 365/207

FOREIGN PATENT DOCUMENTS

0068645 1/1983 European Pat. Off. .
0401792 12/1990 European Pat. Off. .

Primary Examiner—Joseph A. Popek

Assistant Examiner—Huan Hoang

Attorney, Agent, or Firm—Sughrue, Mion, Zinn,
Macpeak & Seas

[57] ABSTRACT

This semiconductor circuit includes a plurality of memory cell arrays arranged mutually adjacent in one direction, a plurality of first selection/sense amplifier circuits provided in the respective regions between mutually adjacent pairs of these memory cell arrays and make access to one of alternately defined odd-numbered or even-numbered memory cell trains in the order of arrangement, two units of second selection/sense amplifier circuits arranged on the outside of the memory cell arrays on both ends of the arrangement of the plurality of memory cell arrays and make access to one of the designated odd-numbered or even-numbered memory cell trains of the memory cell arrays on both ends, a plurality of data buses corresponding to the respective bits of data transferred in bit parallel between an external circuit, and a plurality of input and output switching circuits arranged and connected in one-to-one correspondence to the respective first and second selection/sense amplifier circuits connected to the plurality of data buses so as to have an equal number of memory cell trains capable of transferring data with these data buses, and a plurality of input and output switching circuits which transfer data with the first and the second selection/sense amplifier circuits in one-to-one correspondence.

3 Claims, 4 Drawing Sheets

